

2.5V TO 3.3V HIGH PERFORMANCE CLOCK BUFFER

FEATURES:

- High performance 1:10 clock driver for general purpose applications
- Operates up to 200MHz at VDD = 3.3V
- Pin-to-pin skew < 100ps
- VDD range: 2.3V to 3.6V
- · Output enable glitch suppression
- · Distributes one clock input to two banks of five outputs
- 25Ω on-chip series dampening resistors
- Available in TSSOP package

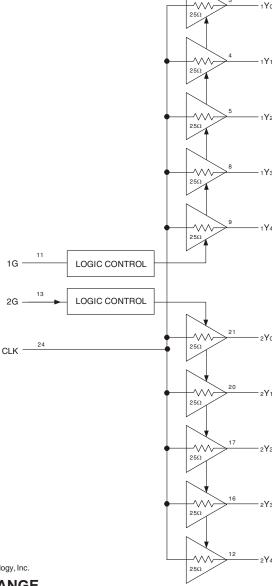
NOTE: EOL for non-green parts to occur on 5/13/10 per PDN U-09-01

DESCRIPTION:

The IDT5V2310 is a high performance, low skew clock buffer that operates up to 200MHz. Two banks of five outputs each provide low skew copies of CLK. Through the use of control pins 1G and 2G, the outputs of banks 1Y(0:4) and 2Y(0:4) can be placed in a low state regardless of CLK input. The device operates in 2.5V and 3.3V environments. The built-in output enable glitch suppression ensures a synchronized output enable sequence to distribute full period clock signals.

The IDT5V2310 is characterized for operation from -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM

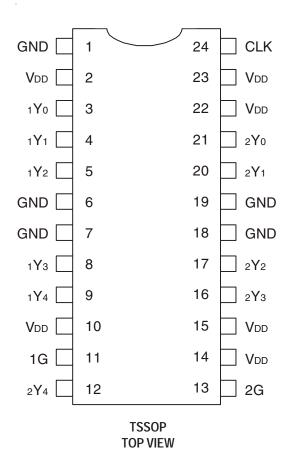


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INDUSTRIAL TEMPERATURE RANGE

DECEMBER 2012

PINCONFIGURATION



ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VDD	Power Supply Voltage	-0.5 to +4.6	V
Vı	Input Voltage ⁽²⁾	-0.5 to VDD +0.5	V
Vo	Output Voltage ⁽²⁾	-0.5 to VDD +0.5	V
lıĸ	Input Clamp Current VI < 0 or VI > VDD	±50	mA
Іок	Output Clamp Current Vo < 0 or Vo > VDD	±50	mA
lo	Continuous Total Output Current Vo < 0 to VDD	±50	mA
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Not to exceed 4.6V.

CAPACITANCE(TA = +25°C, f = 1MHz, VIN = 0V)

Parameter	Description	Min.	Тур.	Max.	Unit
CIN	Input Capacitance	_	2.5	_	pF
	VI = 0V or VDD				

FUNCTION TABLE(1)

	Inputs	Out	outs	
1G	2G	CLK	1 Y (0:4)	2Y(0:4)
L	L	Χ	L	L
Н	L	Н	Н	L
L	Н	Н	L	Н
Н	Н	Н	Н	Н

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - X = Don't Care

PIN DESCRIPTION

TERMINAL		
Symbol	I/O	Description
1G	-	Output Enable Control for $1Y(0:4)$ Outputs. This output enable is active HIGH. If this pin is Logic HIGH, the $1Y(0:4)$ clock outputs will follow the input clock (CLK). If this pin is logic LOW, the $1Y(0:4)$ outputs will drive low independent of the state of CLK.
2G	-	Output Enable Control for $2Y(0:4)$ Outputs. This output enable is active HIGH. If this pin is Logic HIGH, the $2Y(0:4)$ clock outputs will follow the input clock (CLK). If this pin is logic LOW, the $2Y(0:4)$ outputs will drive low independent of the state of CLK.
1Y(0:4)	0	Buffered Output Clocks
2Y(0:4)	0	Buffered Output Clocks
CLK	I	Input Reference Frequency
GND	·	Ground
V _{DD}	PWR	DC Power Supply, 2.3V to 3.6V

RECOMMENDED OPERATING RANGE

Symbol	Description		Min.	Тур.	Max.	Unit
Vdd	Internal Power Supply Voltage	;	2.3	2.5		V
				3.3	3.6	
VIL	Input Voltage LOW	VDD = 3V to 3.6V			0.8	V
		VDD = 2.3V to 2.7V			0.7	
VIH	Input Voltage HIGH	VDD = 3V to 3.6V	2			V
		VDD = 2.3V to 2.7V	1.7			
Vı	Input Voltage		0		Vdd	V
Іон	Output Current HIGH	VDD = 3V to 3.6V			-12	mA
		VDD = 2.3V to 2.7V			-6	
lol	Output Current LOW	VDD = 3V to 3.6V			12	mA
		VDD = 2.3V to 2.7V			6	
TA	Ambient Operating Temperatur	е	-40		+85	°C

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Vik	Input Voltage	$V_{DD} = 3V$, $I_{IN} = -18mA$			- 1.2	V
lin	Input Current	$V_I = 0V \text{ or } V_{DD}$			±5	μΑ
Idd	Static Device Current ⁽¹⁾	$CLK = 0V$ or V_{DD} , $I_{O} = 0mA$, $V_{DD} = 3.3V$			25	μΑ

NOTE:

DC ELECTRICAL CHARACTERISTICS-VDD = 3.3V ± 0.3V

Symbol	Parameter	Test Cor	nditions	Min.	Typ. ⁽¹⁾	Max	Unit
		V _{DD} = Min. to Max.	Іон = -100μА	VDD - 0.2			
Vон	HIGH level Output Voltage	VDD = 3V	Iон = -12mA	2.1			V
			Iон = -6mA	2.4			
		V _{DD} = Min. to Max.	IoL = 100μA			0.2	
Vol	LOW level Output Voltage	VDD = 3V	IoL = 12mA			0.8	V
			IoL = 6mA			0.55	
		VDD = 3V	Vo = 1V	-28			
Іон	HIGH level Output Current	VDD = 3.3V	Vo = 1.65V		-36		mA
		VDD = 3.6V	Vo = 3.135V			-14	
		VDD = 3V	Vo = 1.95V	28			
lol	LOW level Output Current	VDD = 3.3V	Vo = 1.65V		36		mA
		V _{DD} = 3.6V	Vo = 0.4V			14	

NOTE:

^{1.} For IDD over frequency, see TEST CIRCUIT AND WAVEFORMS.

^{1.} All typical values are at respective nominal $\ensuremath{\text{V}_{\text{DD}}}$.

DC ELECTRICAL CHARACTERISTICS - VDD = 2.5V ± 0.2V

Symbol	Parameter	Test Cor	nditions	Min.	Typ. ⁽¹⁾	Max	Unit
Vон	HIGH level Output Voltage	V _{DD} = Min. to Max.	Іон = -100μΑ	V _{DD} - 0.2			V
		VDD = 2.3V	Iон = -6mA	1.8			
Vol	LOW level Output Voltage	V _{DD} = Min. to Max.	IoL = 100μA			0.2	V
		VDD = 2.3V	IoL = 6mA			0.55	
		VDD = 2.3V	Vo = 1V	-17			
Іон	HIGH level Output Current	VDD = 2.5V	Vo = 1.25V		-25		mA
		VDD = 2.7V	Vo = 2.375V			-10	
		VDD = 2.3V	Vo = 1.2V	17			
lol	LOW level Output Current	VDD = 2.5V	Vo = 1.25V		25		mA
		V _{DD} = 2.7V	Vo = 0.3V			10	

NOTE:

TIMING REQUIREMENTS OVER RECOMMENDED RANGE

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
fclk	Clock Frequency	$V_{DD} = 3V \text{ to } 3.6V$	0		200	MHz
		V _{DD} = 2.3V to 2.7V	0		170	

^{1.} All typical values are at respective nominal $\ensuremath{\text{V}_{\text{DD}}}$.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE-

 $V_{DD} = 3.3V \pm 0.3V^{(1)}$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max	Unit
t _{PLH}	CLK to Yx	f = 0MHz to 200MHz	1.3		2.8	ns
tphL						
tsk(o) ⁽²⁾	Output Skew, Yx to Yx				100	ps
tsk(p)	Pulse Skew				250	ps
tsk(pp)	Part-to-Part Skew				500	ps
tr	RiseTime	$Vo = 0.4V \text{ to } 2V^{(3)}$	0.7		2	V/ns
tr	FallTime	$V_0 = 2V \text{ to } 0.4V^{(3)}$	0.7		2	V/ns
tsu	G before CLK↓	V(THRESHOLD) = VDD/2	0.1			ns
tн	G after CLK↓		0.4			

NOTES:

- 1. All typical values are at respective nominal VDD.
- 2. This specification is only valid for equal loading of all outputs.
- 3. Measured at 100MHz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE-

 $V_{DD} = 2.5V \pm 0.2V^{(1)}$

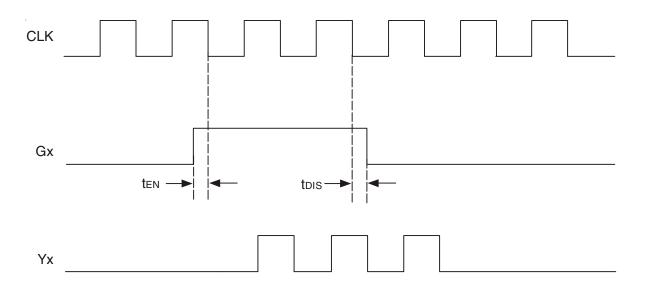
Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max	Unit
t PLH	CLK to Yx	f = 0MHz to 170MHz	1.5		3.5	ns
t PHL						
tsk(o) ⁽²⁾	Output Skew, Yx to Yx				100	ps
tsk(p)	Pulse Skew				400	ps
tsk(pp)	Part-to-Part Skew				600	ps
tr	Rise Time	$Vo = 0.4V \text{ to } 1.7V^{(3)}$	0.5		1.4	V/ns
t⊧	FallTime	$Vo = 1.7V \text{ to } 0.4V^{(3)}$	0.5		1.4	V/ns
tsu	G before CLK↓	V(THRESHOLD) = VDD/2	0.1			ns
tн	G after CLK↓		0.4			

NOTES:

- 1. All typical values are at respective nominal VDD.
- 2. This specification is only valid for equal loading of all outputs.
- 3. Measured at 100MHz.

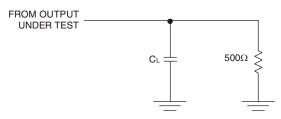
OUTPUTENABLE GLITCH SUPPRESSION CIRCUIT

The purpose of the glitch suppression circuitry is to ensure the output enable sequence is synchronized with the clock input such that the output buffer will be enabled on the next full period of the input clock (negative edge triggered by the input clock). The G input must be stable one ten-time prior to the falling edge of the CLK for predictable operation.



G (ten, tdis) Relative to CLK↓

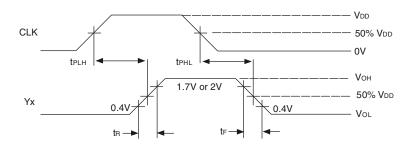
TEST CIRCUITS AND WAVEFORMS



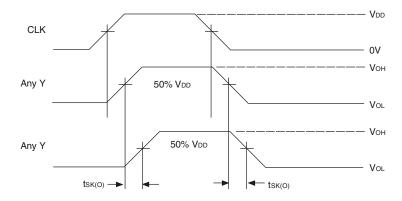
NOTES:

- 1. C_L includes probe and jig capacitance.
- 2. All input pulses are supplied by generators having the following characteristics: PRR \leq 200MHz; Zo = 50Ω ; tR < 1.2ns; tF < 1.2ns.

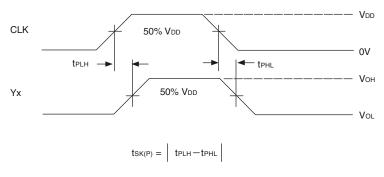
Test Load Circuit



Voltage Waveforms Propagation Delay Times

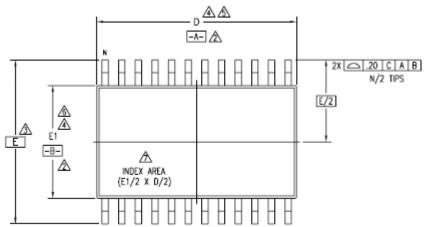


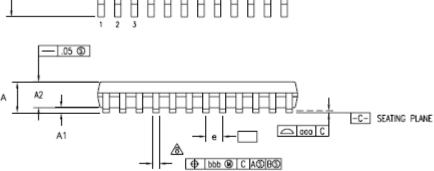
Output Skew

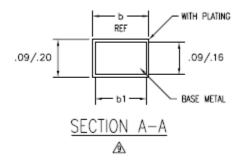


Pulse Skew

PACKAGE DRAWING AND DIMENSIONS (24-PINTSSOP)







JEDE	N		
	AD		N D T E
MIN	NOM	MAX	E
-	-	1.20	
.05	-	.15	
.80	1.00	1.05	
7.70	7.80	7.90	4,5
(6.40 BSC	;	3
4.30	4.40	4.50	4,6
	.65 BSC		
.19	-	.30	
.19	.22	.25	
-			
-	10		

NOTES:

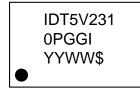
- 1 ALL DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M-1994
- A DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-

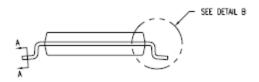
b

- △ DIMENSION E TO BE DETERMINED AT SEATING PLANE —C—
- A DIMENSIONS D AND E1 ARE TO BE DETERMINED AT DATUM PLANE -H-
- DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED .15 mm PER SIDE.
- DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED .25 mm PER SIDE
- DETAIL OF PIN 1 IDENTIFIER IS OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED
- LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION IS .08 mm in excess of the lead width dimension at maximum material condition. Dambar cannot be located on the lower radius or the foot
- THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .10 AND .25 mm FROM THE LEAD TIP
- 10 ALL DIMENSIONS ARE IN MILLIMETERS
- 11 THIS OUTLINE CONFORMS TO JEDEC PUBLICATION 95 REGISTRATION MO-153, VARIATION AA, AB-1, AB, AC, AD & AE

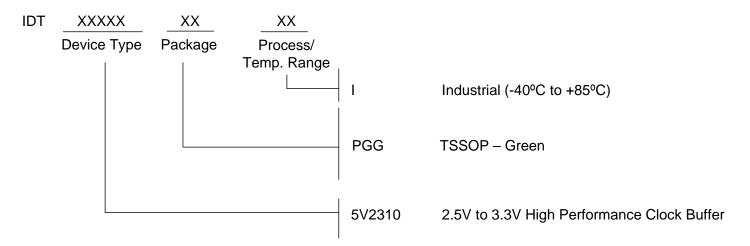
10'-20' R.09 MIN R.09 MIN 10'-20' 10'-20' 10'-8' DETAIL B

MARKING DIAGRAM





ORDERING INFORMATION



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PI6C4931502-04LIE NB7L1008MNG NB7L14MN1G PI49FCT20807QE PI6C4931502-04LIEX ZL80002QAB1 PI6C4931504-04LIEX
PI6C10806BLEX ZL40226LDG1 ZL40219LDG1 8T73S208B-01NLGI SY75578LMG PI49FCT32805QEX PL133-27GC-R
CDCV304PWG4 MC10LVEP11DG MC10EP11DTG MC100LVEP11DG MC100E111FNG MC100EP11DTG NB6N11SMNG
NB7L14MMNG NB3N2304NZDTR2G NB6L11MMNG NB6L14MMNR2G NB6L611MNG PL123-02NGI-R NB3N111KMNR4G
ADCLK944BCPZ-R7 ZL40217LDG1 NB7LQ572MNG HMC940LC4BTR ADCLK946BCPZ-REEL7 ADCLK946BCPZ
ADCLK846BCPZ-REEL7